

## MAINTENANCE MANUAL

## 403-512 MHz SYNTHESIZER/INTERCONNECT BOARD

#### 19D901205G1-3 WIDEBAND

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#### DESCRIPTION

The 403-512 Synthesizer/Interconnect board for Phoenix-SX two-way radio is microcomputer controlled. A phase locked loop synthesizer generates the transmitter and receiver frequencies in a common voltage controlled oscillator (VCO). The frequency range of the VCO is 134.33-185.66 MHz. The frequencies are tripled on the transmit/receive board. The microcomputer also controls the generation of Channel Guard tones and codes and provides the carrier control timer when in the transmit mode.

The Synthesizer/Interconnect board also contains interface circuitry for voltage protection and level shifting, an audio processor, a microcomputer, a frequency synthesizer, a microphone preamplifier, and an electrically erasable PROM (EE PROM). The EE PROM stores the binary data for the transmit and receive frequencies, Channel Guard tones and codes, and the CCT delay on a per channel basis. Eight addresses of the 256 x 4 EEPROM are used for each receive and transmit channel which will include synthesizer, channel guard, and CCT code. A block diagram of the Synthesizer-Interconnect board is shown in Figure 1.

- NOTE -

The FE PROM provides the user with the capability to reprogram the radio to meet changing system requirements.

Programming for the EE PROM is accomplished by using either the General Electric single channel programmer 4EX22A10 on the universal radio programmer TQ2310.

Trademark of General Electric Company U.S.A. Printed in U.S.A. Programming information for the EE PROM is included in the instruction manual for the Programmer.

In addition to providing the normal radio functions, the microcomputer has the ability to execute a maintenance diagnostic instruction set to aid in troubleshooting the radio. Further details are included in the Service Section of this manual.

## CIRCUIT ANALYSIS

## CHANNEL SELECT

Frequency selection is controlled by channel select switch S1. When pressed, A- is applied to microcomputer U801-32, P15 (P15 = port 1 bit 5), causing the microcomputer to advance through the selected channels at the rate of 3 Hz until the switch is released. If the switch is pressed for less than 650 ms the channel selected is advanced by one. After the channel displayed reaches the maximum number of channels programmed in the radio, it will automatically roll over and the next channel displayed will be 1.

When the channel select switch is released, the microcomputer applies +5 VDC to the EE PROM through Q802. The frequency bit code corresponding to the channel displayed is then loaded into the synthesizer. If the channel select switch is pressed while the transmitter is keyed, the microcomputer will unkey the transmitter until the channel select switch is released.

Option indicator H2 is controlled by the CAS line and is turned on when the selected channel is busy.

GENERAL ELECTRIC COMPANY • MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS • LYNCHBURG, VIRGINIA 24502 U.S.A.



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# CIRCUIT ANALYSIS

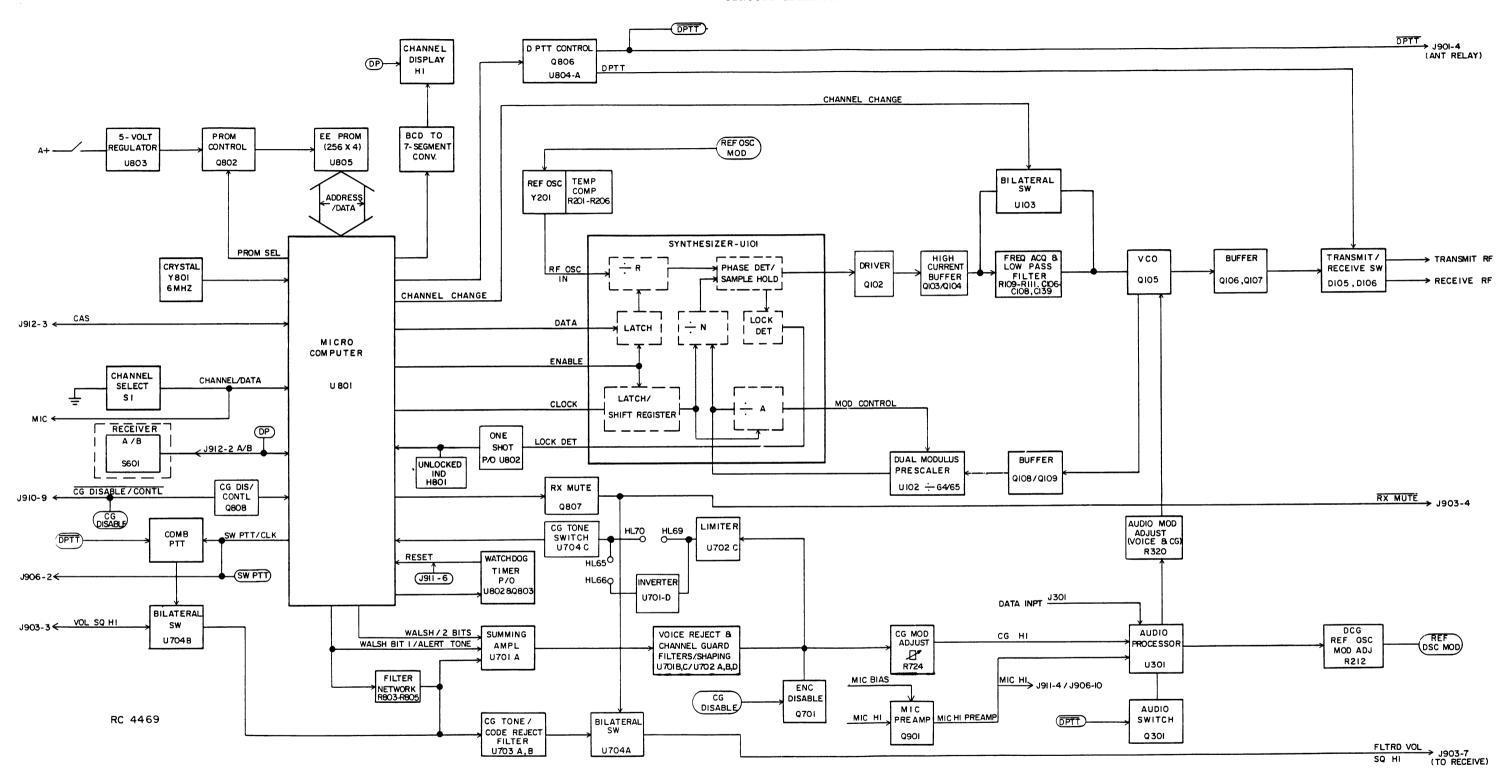


Figure 1 - Synthesizer/Interconnect Board

MODE A/B

Mode A/B switch S601 doubles the channel selection capability of the radio. S601 is located on the transmit/receive board.

Fight address locations are used in the EE PROM for each transmit and receive frequency. The display is capable of displaying channels one through eight. By operating the A/B pushbutton switch the user can select two independent transmit and receive frequencies per channel displayed, providing the radio with up to 16 independent transmit and receive frequencies.

Mode B is indicated by an illuminated decimal point on the 7 segment display. 8.5V CONT is applied to the DP input from the MODE A/B switch on the Tx/Rx board.

The Mode A/B switch may be used to provide mobile-to-mobile communications through an intermediate repeater (repeated path) or direct mobile-to-mobile communications. For example: channel 1 Mode A may be progammed for the repeater frequency (repeated path) while channel 1 Mode B would be programmed for the mobile receive frequency (direct path). Judicious programming will allow selection of repeated or direct communication paths on selected channels.

# MICROCOMPUTER CONTROL SYSTEM

The microcomputer responds to the manually initiated functions of Push-to-talk, Channel Select, and Mode A/B. All other operations occur automatically and are controlled by the microcomputer.

When the PTT switch is pressed A- is applied to microcomputer U801-38 from J911-2. The microcomputer immediately mutes the receiver by turning on Q807 which provides a low level to J903-4 to mute the receiver. The microcomputer then delays 10 milliseconds before loading the synthesizer with the transmit bit code. This allows the audio amplifier to be turned off before the synthesizer frequency is changed. After this delay the microcomputer turns on PROM power switch C802, applying +5V to EE PROM U805. The transmit bit code is then loaded in parallel from the PROM into the microcomputer and then serially into the frequency synthesizer over the clock and data input lines.

Once the bit stream is loaded into the synthesizer an enable pulse and a 10 millisecond channel change pulse is provided to allow the synthesizer to generate the correct RF frequency. The microcomputer immediately begins monitoring the LOCK DET line to verify that the

synthesizer is 'on' frequency. If the synthesizer is not locked on the correct frequency negative pulses will be present on the LOCK DET line and the microcomputer will reload the synthesizer in an attempt to lock it on frequency. If the synthesizer is locked on the correct frequency, the microcomputer will key the transmitter by pulling the input line to inverter U804A low. This allows the output of U804A to rise to +8.5 VDC, forward biasing transmit select diode D105, permitting the synthesizer generated RF frequency to pass through to the exciter through P151. Minimum RF output level at this point is 8.0 dBm. Typical attack time of the transmitter is 50 milliseconds.

At the same time transistor Q806 is turned on, applying  $\overline{DPTT}$  to audio switch Q301. Q301 is also turned off, removing the 'short' from amplifier U301A and enabling the audio processor.

#### WATCHDOG TIMER

The watchdog timer consisting of reset switch Q803 and timer U802, monitors the operation of the microcomputer and generates a reset pulse in the unlikely condition that the microprocessor fails to function properly.

When the microcomputer is operating properly, reset pulses from U801-35 are applied to the base of reset switch Q803 through delay network R836 and C805. Q803 turns on, grounding the clock timer input which, in turn, holds the microcomputer RESET input high.

When the microcomputer is not functioning properly, the reset pulses will not be present. Q803 will turn off and the timer will generate a square wave to reset the microcomputer.

#### FREQUENCY SYNTHESIZER

The frequency synthesizer generates the transmit and receive frequencies for all channels under control of the microcomputer. The frequency synthesizer consists of a reference oscillator Y201, synthesizer IC U101, bilateral switch U103, low pass filter, VCO Q105, buffers Q106 and Q107, and high speed dual modulus prescaler U102.

## Reference Oscillator

The reference oscillator consists of Y201, a junction FET Q201, varicap D201, tuned coll L201, and associated circuitry. The 5 PPM Colpitts oscillator operates at a frequency of 13.2 MHz. Voltage is provided by the 8.5V continuous supply. A temperature compensation network consisting of R201 thru R206,

provides a temperature compensated voltage to varicap D201 to maintain the correct frequency. The temperature compensator, utilizing an inverse DC S-curve output characteristic, varies the output voltage to the varicap as a function of temperature. The temperature compensation network maintains frequency over a temperature range of -30°C to +60°C (-22°F to +140°F). The varicap is also used to modulate the oscillator.

Diode D202 produces a negative DC level at the gate of FET Q201 depending on the amplitude of the oscillations. This, in effect, produces a negative feedback, RF to DC, and prevents the oscillator from going into limiting. Slug tuned coil L201 sets the frequency of the oscillator. Modulation voltage from the audio modulator is applied to the reference oscillator through R214. Modulation is adjusted by R212 and applied to varicap D201 through C201 and R209. R212 adjusts the deviation. Refer to the service section for adjustment procedures.

The synthesizer IC contains three dividers, a phase detector, two shift registers, and a lock detect circuit. When the PTT switch is pressed (transmit), released (receive), or a different channel selected, new frequency data is received on the clock, data, and enable lines and the synthesizer immediately begins generating the new RF frequency. This serial data determines the VCO frequency by setting the internal dividers. The reference oscillator frequency applied to the programmable divide by R counter is divided down to some lower frequency as indicated by the input data and applied to the internal phase detector.

The phase detector compares this signal with the output of the internal - N counter. The output of the - N counter is a function of the RF frequency which is divided down by the dual modulus prescaler and the - N counter. When operating on the correct frequency the inputs to the phase detector are identical and the output voltage of the phase detector is constant. Under these conditions, the VCO is stabilized or locked on frequency. If the compared frequencies (phases) differ a + error voltage is generated and applied to 0102. This error voltage is then supplied to the VCO through the frequency acquisition circuit and low pass filter. The capacitance of varicap D102 varies in accordance with the applied error voltage, thereby resetting the VCO to the correct frequency. Capacitor C104 is a holding capacitor to store the 'hold' voltage for the phase detector/ sample and hold circuit. C105 is a ramp capacitor which also is part of the sample and hold circuit. The value of C105 determines the rate of charge of the ramp.

The lock detect line provides lock status information to the microcomputer through a one shot FF (part of U802).

## Acquisition and Low Pass Filter

The output of the synthesizer is applied through driver Q102 and high current buffers Q103 and Q104 to the low pass filter. The low pass filter consisting of R109-R111, and C106-C108 eliminates undesired pulses on the VCO error control line to provide a constant DC level to frequency adjusting varicaps D102 and D104.

When a channel change pulse is received bilateral switch U103 is turned on to bypass the low pass filter effectively increasing the bandwidth and decreasing channel acquisition time. The channel change pulse is 10 milliseconds wide.

## Voltage Controlled Oscillator VCO

The VCO is a wide range JFET oscillator with an operating range of 134.33-185.66 MHz. The divided down reference frequency is 4.1666 kHz. VCO frequency is controlled by an error control voltage from the synthesizer and set by varicap D102. Frequency range centering is provided by L102. Audio modulation is provided by the audio processor and applied to the VCO through C138 and R116.

The output of the VCO is taken from the source of Q105 and applied to RF output buffers Q106 and Q107. These buffers provide drive for receiver injection, transmitter exciter, and feedback buffers Q108 and Q109.

## Transmit and Receive Switch

A transmit/receive PIN diode switch, D105 and D106 directs the RF output to the transmitter or receiver. The switch is controlled by the DPTT signal from the microcomputer. When DPTT is high, D105 conducts and RF is fed to the transmitter and to the receiver when DPTT is low, allowing D106 to conduct.

## Dual Modulus Counter

The VCO frequency is fed back to dual modulus prescaler U102, through buffers Q108 and Q109. The counter divides the VCO frequency by 64 or by 65 depending on the status of the modulus control line. The divided down reference frequency is 4.16 kHz.

The output of the dual modulus counter is applied to the :N counter in the synthesizer. It is then divided down and compared in frequency and phase with the divided down frequency from the reference oscillator. The :N count is set by the microcomputer.

#### MICROPHONE PREAMPLIFIER

A preamplifier stage (Q901 and associated circuitry) is provided for the standard electret microphone without a built-in preamplifier.

With this microphone, MIC HI is coupled through J911-5 to the preamplifier stage. The amplified output is coupled through C312 and R301 to the audio processor.

For optional microphones with a huilt-in preamplifier, audio is coupled through J911-4, bypassing MIC PRE AMP 0901.

Mic bias is provided by the 8.5V CONT Source through bias network R904-906.

# AUDIO PROCESSOR

The audio processor provides audio pre-emphasis with amplitude limiting and post limiter filtering. A total gain of approximately 24 dB is realized through the audio processor. 20 dB is provided by U301B and 4 dB by U301A.

The 8.5 Volt regulator powers the audio processor and applies regulated +8.5V through J903-2 to a voltage divider consisting of R306 through R309. The +4.25V output from the voltage divider at the junction of R307 and R308 establishes the operating reference point for both operational amplifiers. C305 provides an AC ground at the summing input of both operational amplifiers.

Audio direct from the microphone is coupled to the audio processor through C312 and R301 to the input of operational amplifier U301B-6.

When the input signal to U301B-6 is of a magnitude such that the amplifier output at U301B-7 does not exceed 4 volts P-P, the amplifier provides a nominal 20 dB gain. When the audio signal level exceeds 4 volts peak-to-peak, diodes D301 and D302 conduct on the positive and negative half cycles providing 100% negative feedback to reduce the amplifier gain to 1. This limits the audio amplitude at U301B-7 to 5 volts peak-to-peak.

Resistors R303, R304, R305, and capacitor C302 comprise the audio preemphasis network that enhances the signal to noise ratio. R304 and C302 control the pre-emphasis curve below limiting. R305 and C302 control the cut-off point for high frequency pre-emphasis. As high frequencies are attenuated, the gain of U301B is increased.

The amplified output of U301B is coupled through C307, R313 and R314 to a second operational amplifier U307A.

The Channel Guard tone and data inputs are applied to U301A-2. The CG tone (or data) is then combined with the microphone audio.

A post limiter filter consisting of R314, R313, R315, C308 and C309 provide 12 dB per octave roll-off. R313 and C307 provide an additional 6 dB per octave roll-off for a total of 18 dB.

#### - SERVICE NOTE -

R313-R315 are 1% resistors. This tolerance must be maintained to assure proper operation of the post limiter filter. Use exact replacements.

The audio processor output is coupled through the audio and REF OSC modulation controls to the transmitter. R212 and R320 set the modulation sensitivity for the VCO and reference oscillator.

Shorting switch Q301 is turned on in the receive mode (DPTT is high) to short out U301-A and prevent any interference from the transmit audio circuits.

#### CHANNEL GUARD

Channel Guard provides a means of restricting calls to specific radios through the use of a continuous tone coded squelch system (CTCSS) or a continuous digital coded system (CDCSS). Tone frequencies range from 71.9 Hz to 210.7 Hz. There are 83 standard programmable digital codes. These codes and frequencies are listed in the Programmers Manual.

The microcomputer selects the assigned code/tone information from the EE PROM memory for each channel, transmit and receive, and generates the Channel Guard signal. This signal is applied as Walsh Bit 1 and 2 to summing amplifier U701A. These two bits are summed together and filtered to provide a smooth sine wave for tone Channel Guard. For CDCSS Channel Guard units, walsh bit 2 is used to generate squarewaves.

The switched volume/squelch Hi signal to the summing amplifier is controlled by bilateral switch U704B. In the encode mode COMB DPTT is low turning U704B off and preventing any input from the SW Vol/Sq Hi line from interfering with the encoding signal.

The output of summing amplifier U701A is applied to buffer/amplifier U702B through a two-pole active voice reject filter consisting of U701B and C and U702A and D. The active filter shunts all frequencies above 300 Hz to ground, thereby preventing those

frequencies from interfering with the encoded signal. The output of U702B is the assigned CG tone or digital signal. This signal is applied to the audio processor through CG deviation control R724. Channel Guard deviation is set for 0.75 kHz.

# CG Decode

In the decode mode COMB DPTT is high, U704B is turned on and audio from the SW Vol/Sq Hi line is applied to summing amplifier U701A through bilateral switch U704B. This signal is amplified and filtered by U701A, B, C and U702A, B and D, so that only the CG signal (if present) is applied to hard limiter U702C. The CG signal is squared up for comparison by the microcomputer to determine if the CG signal is correct. If the microcomputer determines the CG signal to be correct, RX Mute transistor 0807 is turned off. The Rx Mute line is pulled high by pull up resistor R715 through D819. This turns on bilaterial switch U704A and allows the audio on the FLTRD VOL/SQ HI line to pass through to the receiver.

# CHANNEL GUARD (CG) DISABLE

The CG DIS line has a double function. It can disable the encode or the decode CG function. The encode disable function is controlled by the PTT switch while the decode function is disabled within the microcomputer software. To disable the decoder, the CG DIS/CONTL line should be grounded. The microcomputer will detect that the line is low, and turn RX MUTE transistor Q807 off. The decode filter/limiter circuit is not affected, it continues to operate. The detection software also does not stop working. This allows the off hook STE to function.

When the CG DIS line is pulled high (>8.5V), the microcomputer does not sense any changes. Channel Guard disable transistor 0701 will turn on when the CG DIS line goes above 8.5 V and shorts the output of the filter to ground. This disables the encoder by preventing any signal from going out on CG HI and will also disable the decoder since no limited CG tone will go to the microcomputer. The receiver will be muted since no CG is decoded. Disabling the decoder this way will never allow the audio to open up, while taking the radio off hook (pulling CG DIS low) will always make the radio open up. Turning CG Disable transistor 0701 on causes the DC bias to change. It will take 2 or 3 seconds for the bias to restore itself after the encoder is disabled.

# SQUELCH TAIL ELIMINATION (STE)

STF eliminates squelch tails when the radio is on book or off book. When

Channel Guard is disabled (off hook) the decoder is still looking at the received signal. The RX MUTE line is high, as would be normally expected. The Channel Guard decoder is looking for the STE burst (phase reversal in tone Channel Guard, STE tone in Digital Channel Guard.) If an STE burst is detected, the RX MUTE line will go low for about 200 ms. This will prevent the squelch tail from being heard. After 200 ms, the RX MUTE line will go high again; by now the transmission has ended and the squelch will hold the audio closed. The off hook STE does not affect the operation of the Channel Guard while on hook. Another way of looking at it: the radio will go quiet for 200 ms any time STE is detected. If it was on hook it will stay quiet after the 200 ms, if it was off hook it will revert to noise squelch operation. operates only on the tone the radio is programmed to receive. If the signal has a Channel Guard tone the radio is not programmed to receive and the microphone is off-hook, STE will not be active. CDCSS STE works regardless of the code.

## Data Polarity Inversion

In some instances it is necessary to invert the polarity of the digital Channel Guard signal to enhance system compatability. Inverted polarity normally results in a wrong code or one that cannot be used. When this occurs, remove jumper cable W701 and connect a jumper wire between HL65 and HL69 and HL66.

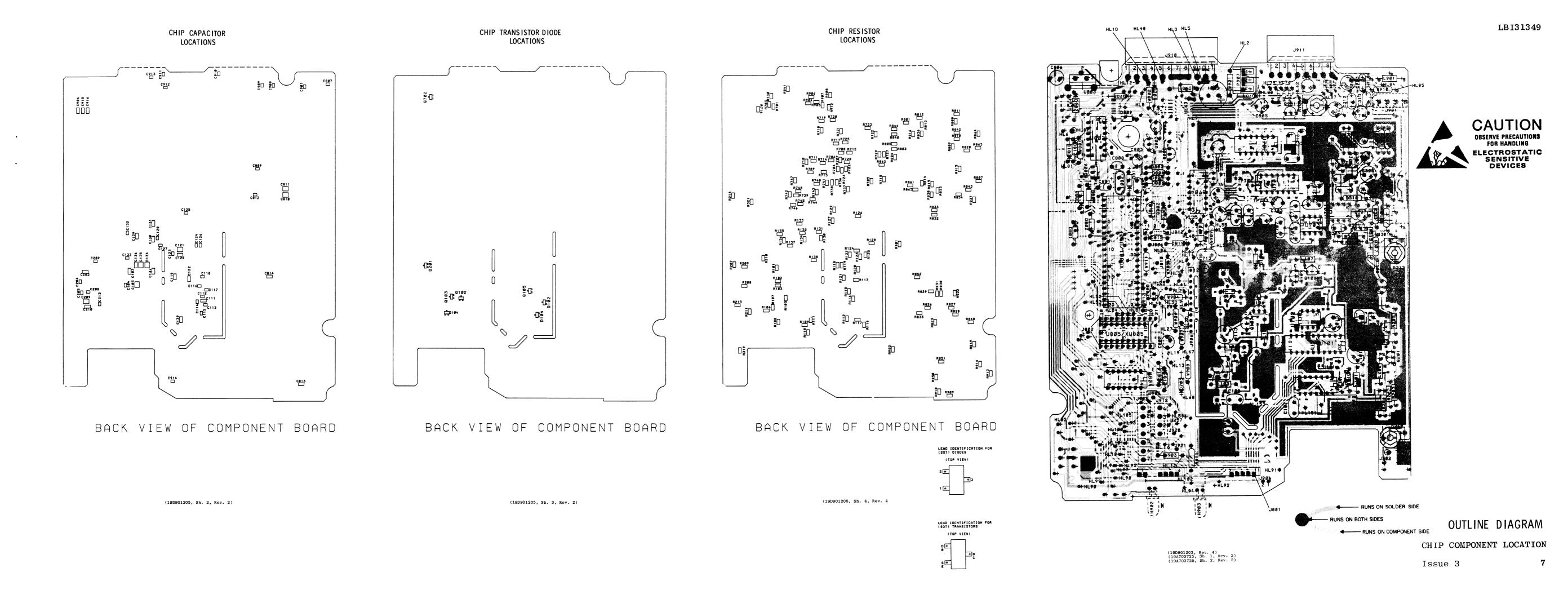
# CARRIER CONTROL TIMER

The Carrier Control Timer (CCT) is contained within and controlled by the microcomputer. Each time the PTT switch is activated an internal counter begins to count down. If the counter times out, the transmitter is unkeyed and a 100 mV rms 1 kHz tone is sounded until the microphone is unkeyed. The CCT is set for 1 minute.

# CHANNEL MEMORY

In radios equipped with a type 8749 microcomputer, channel memory allows channel selection and display at any time. It is not dependent upon switched A+ (ignition turn on). Channel memory is enabled by removing W801 and adding insulated DA jumper from H63 to H64 - all on the Interconnect/Synthesizer board.

In radios equipped with a type 8049 microcomputer a separate 5 volt regulator, U2, on the display board, supplies current for channel memory. When the type 8049 microcomputer is used, J4 is connected to J810, J3 is connected to J811, and W911 is removed.



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| FUNCTION  | CPNT<br>SERIES           |
| CG TONE REJECT FILTER<br>5V REGULATOR<br>SYSTEM                       | 700<br>800<br>900        |
| SYSTEM/REF OSC  | 3                        |
| FUNCTION  | CPNT<br>SERIES           |
| SYNTHESIZER REF OSC<br>TX AUDIO PROCESSOR<br>SYSTEM CONTROL<br>SYSTEM | 200<br>300<br>800<br>900 |
| SYNTHESIZER/C.G   | 4                        |
| FUNCTION  | CPNT<br>SERIES           |
| SYNTHESIZER<br>CHANNEL GUARD  | 100<br>700               |
| SYSTEM  | 5                        |
| FUNCTION  | CPNT<br>SERIES           |
| MICROCOMPUTER CONTROL<br>MULTI FREG DISPLAY                           | 800<br>A901              |

| DEVICE | 5V<br>PIN NO | GND<br>PIN NO | 8.5V CONT<br>PIN NO | B.5V SYN<br>PIN NO |
|--------|--------------|---------------|---------------------|--------------------|
| U103   | FIN NO       | 1,7,10,12,13  | 7 11 110            | 14                 |
| U301   |              | 4             | 8                   |                    |
| U701   |              | 11            | 4                   |                    |
| U702   |              | 11            | 4                   |                    |
| U703   |              | 4             | 8                   |                    |
| U704   |              | 7,10,12       | 1 4                 |                    |
| U804   | 14           | 7             |                     |                    |

# SPARE IC FUNCTION

| DEVICE | INPUT<br>PIN NO | OUTPUT<br>PIN NO | CONTROL<br>PIN NO |
|--------|-----------------|------------------|-------------------|
| U103-A | - 1             | 2                | 13                |
| U103-D | 10              | 11               | 12                |
| U704-D | 10              | 11               | 12                |

ALL CHIP RESISTORS ARE 1/8 WATT.

ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED.

RESISTOR VALUES IN \( \Omega\) UNLESS FOLLOWED BY MULTIPLIER k, OR M.

CAPACITOR VALUES IN F UNLESS FOLLOWED BY MULTIPLIER u, n OR, p.

INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER m, n OR u.

|      | COMPONENT   | 10 | ENTIFICATION    | CH | ART         |    |
|------|-------------|----|-----------------|----|-------------|----|
| PART | G1,613      |    | G2.G14          |    | G3,G15      |    |
|      | 440-470 MHZ | WB | 470-512 MHZ     | WB | 403-440 MHZ | WB |
| C113 | 33p         |    | 33 <sub>P</sub> |    | 100p        |    |
| C114 | 27p         |    | 10P             |    | 27₽         |    |
| C115 | 1.0p        |    | 1.0p            |    | 1.2P        |    |
| L106 | 180n        |    | 150n            |    | 220n        |    |

| 10DEL NO.   | DESCRIPTION                    | REV. LTR |
|-------------|--------------------------------|----------|
| 9090120561  | 440-470 MHZ WB                 | F        |
| 9D901205G2  | 470-512 MHZ WB                 | F        |
| 9D901205G3  | 403-440 MHZ WB                 | F        |
| 9D901205G13 | 440-470 MHZ WB (GOLD CONTACTS) |          |
| 9D901205G14 | 470-512 MHZ WB (GOLD CONTACTS) |          |
| 90901205615 | 403-440 MHZ WB (GOLD CONTACTS) |          |

# SCHEMATIC DIAGRAM

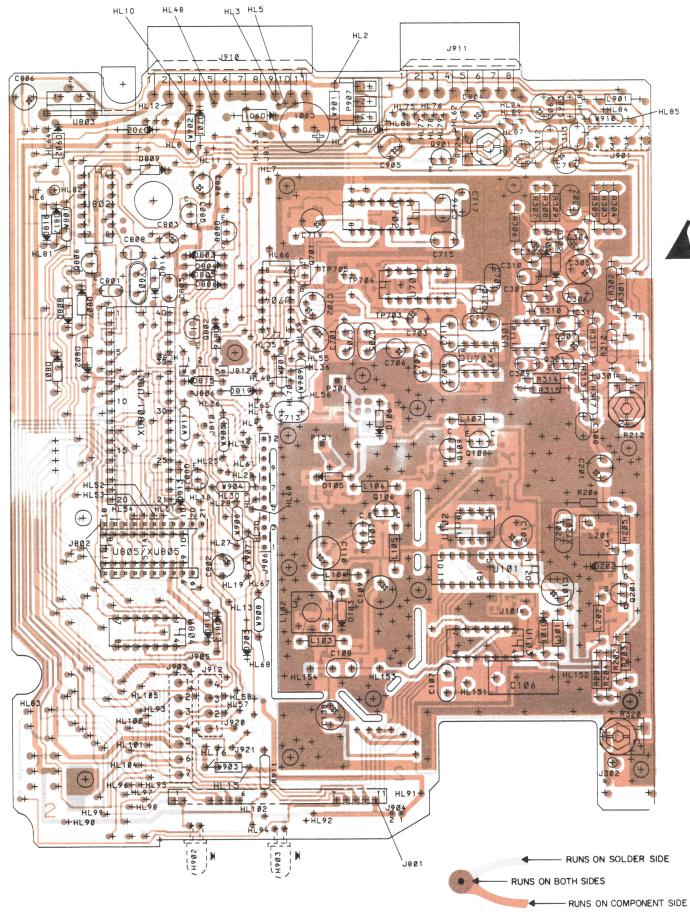
SYNTHESIZER/INTERCONNECT BOARD LEGEND INFORMATION

Issue 3

(19D901202, Sh. 1, Rev. 9)

# NOTES:

- ↑ FOR T99 DECODER, ADD JUMPERS HL7 TO HL9, HL12 TO HL14, HL39 TO HL40, HL48 TO HL60, HL19 TO HL55. OMIT JUMPERS W905, W909, W908, W907.
- FOR PUBLIC ADDRESS OPTION, ADD JUMPERS HL60 TO HL48, HL3 TO HL4, HL8 TO HL9, HL12 TO HL14.0MIT JUMPERS W902, W906, W904, W908. MIC WITHOUT PREAMP REQUIRES HL61 TO HL62 JUMPER AND DELETE W905.
- FOR CHANNEL MEMORY (200 MA MAXIMUM CONTINOUS BATTERY DRAIN) WHEN USING UV ERASABLE U801 (8749) ADD INSULATED JUMPER HL63 TO HL64 AND OMIT W801.
- A FOR IGNITION SWITCH CONTROL, REMOVE JUMPER W901.
- FOR SPEAKER MUTE FUNCTION WITH THE UNIVERAL TONE CABLE OPTION WITHOUT PA OPTION, OMIT JUMPER W903, ADD JUMPER HLS TO HL6 (NOT COMPATIBLE WITH INTERNAL/EXTERNAL SPEAKER). WITH PA OPTION, OMIT W903 ONLY.
- FOR EXTERNAL SPEAKER OPTION, REMOVE JUMPER W903 TO DISABLE THE INTERNAL SPEAKER.
- A PRESENT FOR UNITS WITHOUT MULTI-FREQ DISPLAY.
- FOR 2.5 PPM OPERATION, REPLACE Y201 WITH 19870304967.
- 11.\* DENOTES CHIP COMPONENTS (EXAMPLE R1\*),
  WHICH ARE LOCATED ON SOLDER SIDE OF PWB.
- 12. DENOTES A- COMMON TO CHASSIS.
- TO INVERT DIGITAL CHANNEL GUARD DECODE POLARITY, REMOVE \$701 AND ADD A JUMPER FROM HL66 TO HL65.
- THE FOLLOWING JUMPERS ARE IMPLEMENTED USING ONE OHM RESISTORS. W701, W801, W904, W905, W906, W907, W908, W909, W910 AND W911. CLIP BOTH LEADS TO REMOVE JUMPER.
- THE FOLLOWING JUMPERS ARE IMPLEMENTED USING ZERO OHM "RESISTORS". W901, W902, AND W903.CLIP BOTH LEADS TO REMOVE JUMPER.
- FOR CHANNEL MEMORY (15 MA CONTINUOUS
  BATTERY DRAIN) ONLY WITH MASKED VERSION (8049)
  OF U801 CONNECT A901,A902,A903-J4 TO J810
  AND A901,A902,A903-J3 TO J811 AND REMOVE W911.
- FOR INTERNAL/EXTERNAL SPEAKER OPTION
  WITH SWITCH (EXTERNAL TO RADIO) DELETE
  W903 AND ADD JUMPER HL5 TO HL6.
- FOR UNITS WITH 199 OPTION OR PUBLIC ADDRESS OPTION WITH MULTI-FREQ DISPLAY, REMOVE R911 AND R8.
- FOR PSLM OPTION C106 AND C108 ARE REPLACED WITH NEW PARTS SUPPLIED IN PSLM MOD KIT FOR IMPROVED SYNTHESIZER SWITCHING PERFORMANCE.
- FOR PHOENIX INTERNATIONAL, ADD JUMPERS HL24 TO HL60, HL40 TO HL39, HL4 TO R302, HL14 TO HL48. REMOVE W905, D918 AND C713.
- PART OF HARDWARE KIT 19A701522.



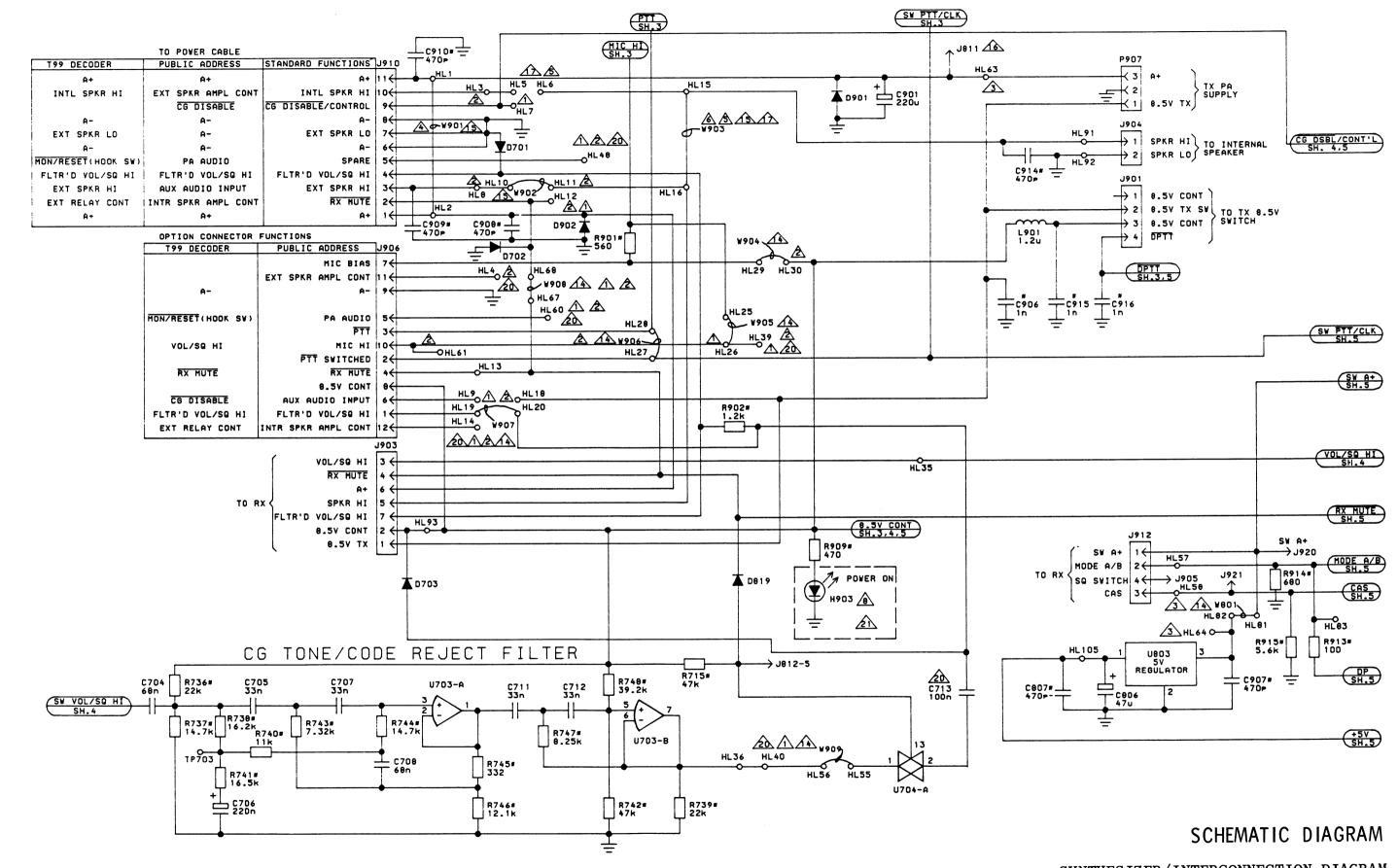
CAUTION

OBSERVE PRECAUTIONS
FOR HANDLING

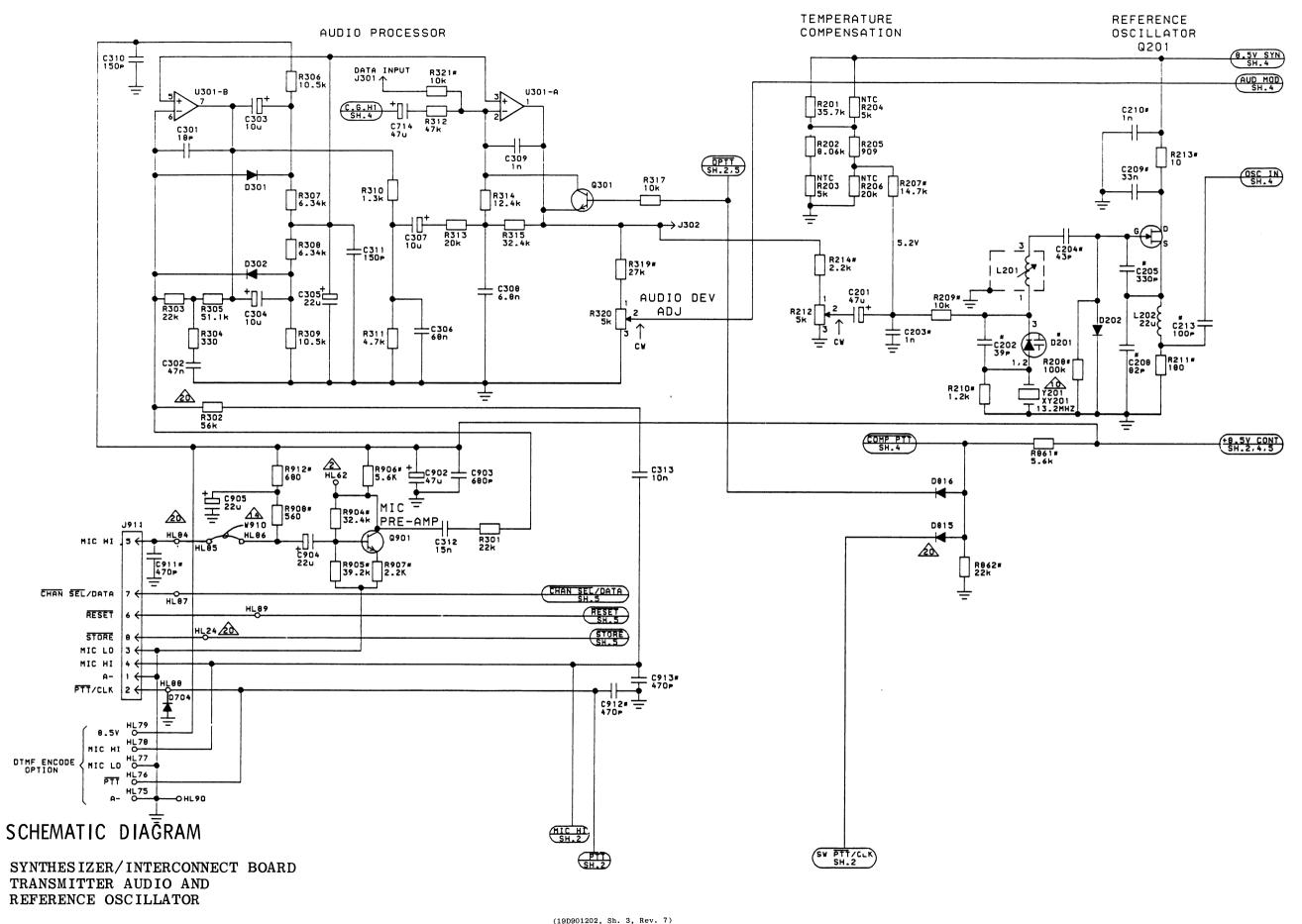
ELECTROSTATIC
SENSITIVE
DEVICES

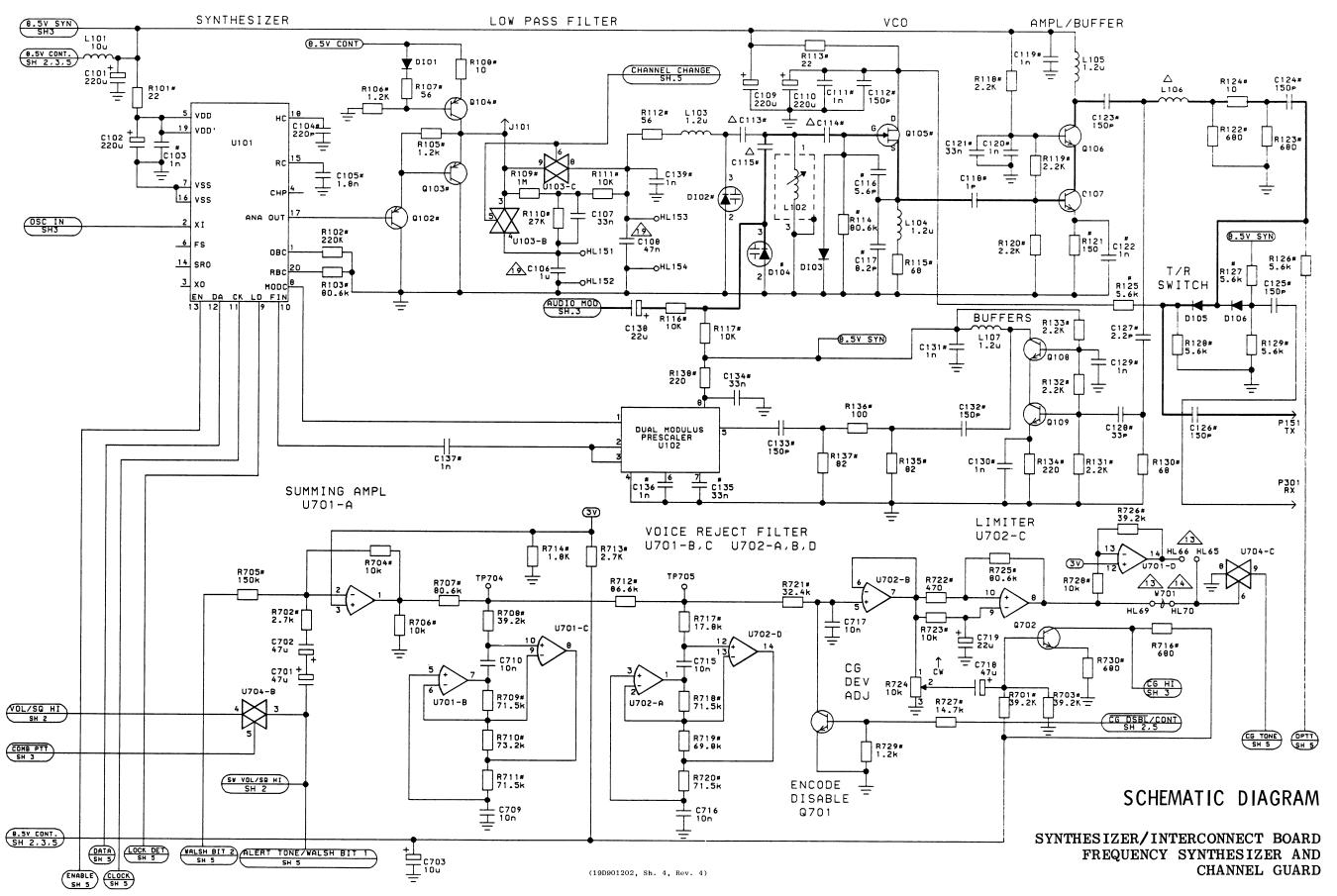
OUTLINE DIAGRAM

CHIP COMPONENT LOCATION



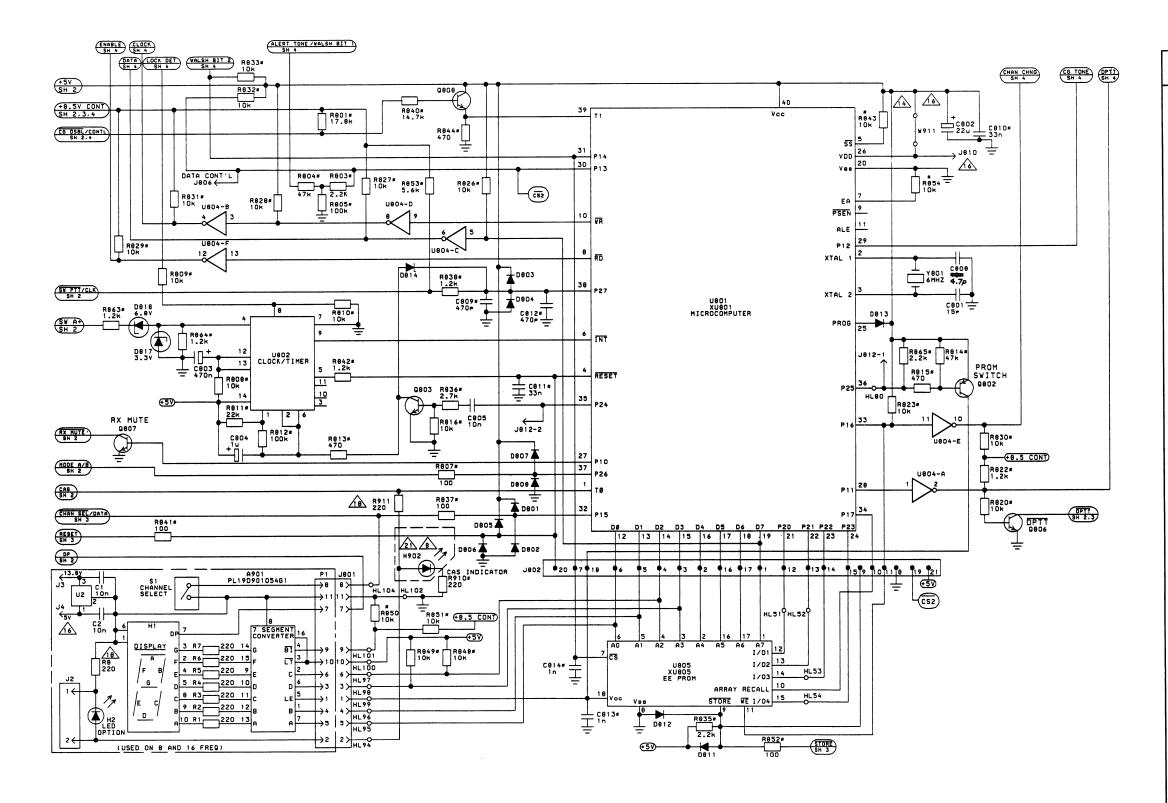
SYNTHESIZER/INTERCONNECTION DIAGRAM INTERFACE AND CHANNEL GUARD FILTER





Issue 3

DISPLAY BOARD 19D901054G1 ISSUE 2



| S | CHEN | TAN | IC | DIA | GRAM |
|---|------|-----|----|-----|------|
|   |      |     |    |     |      |

(19D901202, Sh. 5, Rev. 5)

SYNTHESIZER/INTERCONNECT BOARD SYSTEM CONTROL

| SYMB0L           | GE PART NO.                | DESCRIPTION   |
|------------------|----------------------------|---|
|                  |                            |   |
| C1               | 19A700121P6                |   |
| and<br>C2        | 13470012170                | -   |
|                  |                            |   |
| H1               | 19A134712P5<br>19A134354P9 | Optoelectronic display: green; sim to HOSP 3603.  Optoelectronic: yellow: HP sim to HLMP4719. |
| Н2               | 194134354P9                |   |
|                  | 19A700072P28               | Printed wire: 2 contacts rated @ 2.5 amps; sim  |
| J2               |                            | to Molex 22-27-2021.  |
| J3<br>and<br>J4  | 19A703248P1                | Contact, electrical.  |
|                  |                            |   |
| P1               | 19A703248P3                | Contact, electrical. (Quantity 11).   |
|                  |                            | RESISTORS   |
| R1<br>thru<br>R8 | 19A700019P29               | Deposited carbon: 220 ohms ±5%, 1/4 w.  |
|                  |                            |   |
| 81               | 19A701324P2                | Push: contacts rated 1 mA at 10 volts; sim to MDP Module.                                     |
|                  |                            |   |
| U1               | 19A700029P204              | Digital: BCD-TO-SEVEN SEGMENT<br>LATCH/DECODER/DRIVER.  |
| U2               | 19J706031P1                | Linear: POSITIVE VOLTAGE REGULATOR.   |
|                  |                            | MISCELLANEOUS   |
|                  | 19A701341P2                | Spacer. (Used with S1).   |
|                  | 19C850665P1                | Pushbutton. (S1).   |
|                  | 19A701699P5                | Nameplate. (Located on S1 pushbutton).  |
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#### PARTS LIST

403 - 512 MHZ SYNTHESIZER/INTERCONNECT BOARD 19D901250G1 440-470 MHz 19D901250G2 470-512 MHz 19D901250G13 430-440 MHz 19D901250G13 440-470 MHz (Gold Contacts) 19D901250G15 403-440 MHz (Gold Contacts)

| SYMBOL               | GE PART NO.   | DESCRIPTION   |
|----------------------|---------------|---|
|                      |               |   |
|                      |               | NOTE: WHEN REPLACING BOARDS, CARE SHOULD BE TAKEN TO ASSURE BOARDS WITH GOLD CONTACTS ARE NOT INTERCHANGED WITH BOARDS HAVING TIN CONTACTS. |
|                      |               | SYNTHESIZER   |
|                      |               |   |
| 0101<br>and<br>0102  | 19A703314P2   | Electrolytic: 220 uF-10 + 50%, 10 VDCW.   |
| 2103                 | 19A702061P99  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.  |
| 2104                 | 19A702061P69  | Ceramic: 220 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/*C.   |
| 2105                 | 19A702061P91  | Ceramic: 1800 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/*C.  |
| C106                 | 19A700004P8   | Metallized polyester: 1 uF ±10%, 63 VDCW.   |
| C107                 | T644ACP333K   | Polyester: 0.033 uF ±10%, 50 VDCW.  |
| :108                 | 19A702250P111 | Polyester: 047 uF ±10%, 50 VDCW.  |
| 109<br>nd<br>110     | 19A703314P2   | Electrolytic: 220 uF-10 + 50%, 10 VDCW.   |
| 2111                 | 19A702061P99  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/*C.  |
| 112                  | 19A702061P65  | Ceramic: 150 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/*C.   |
| 2113                 | 19A702236P38  | Ceramic: 33 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/*C.  |
| 113                  | 19A702236P50  | Ceramic: 100 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.   |
| 114                  | 19A702236P36  | Ceramic: 27 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM. *C.   |
| :114                 | 19A702236P25  | Ceramic: 10 pF ±.5 pF, 50 VDCW, temp coef 0 ±30 PPM/°C.   |
| 115                  | 19A702236P6   | Ceramic: 1.0 pF ±.25 pF, 50 VDCW, temp coef 0 +30 PPM/°C.   |
| 115                  | 19A702236P7   | Ceramic: 1.2 pF ±.25 pF, 50 VDCW, temp coef 0 ±30 PPM/°C.   |
| 116                  | 19A702236P19  | Ceramic: 5.6 pF ±.5 pF, 50 VDCW, temp coef 0 ±30 PPM/°C.  |
| 117                  | 19A702236P23  | Ceramic: 8.2 pF ±.25 pF, 50 VDCW, temp coef 0 +30 PPM/°C.   |
| 118                  | 19A702236P6   | Ceramic: 1.0 pF ±.25 pF, 50 VDCW, temp coef 0 ±30 PPM/*C.   |
| 119<br>nd<br>120     | 19A702061P99  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.  |
| C121                 | 19A702052P20  | Ceramic: 0.033 uF ±10%, 50 VDCW.  |
| 122                  | 19A702061P99  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.  |
| 0123<br>thru<br>0126 | 19A702061P65  | Ceramic: 150 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.   |
| 2127                 | 19A702236P10  | Ceramic: 2.2 pF ±2.5 pF, 50 VDCW, temp coef 0 +30 PPM/*C.   |
| 128                  | 19A702236P38  | Ceramic: 33 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.  |
| 129<br>hru<br>131    | 19A702061P99  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.  |
| 2132                 | 19A702061P65  | Ceramic: 150 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/*C.   |

| SYMBOL       | GE PART NO.                    | DESCRIPTION   | SYMBOL               | GE PART NO.   | DESCRIPTION  |
|--------------|--------------------------------|---|----------------------|---------------|--|
| C134         | 19A702052P20                   | Ceramic: 0.033 uF <u>+</u> 10%, 50 VDCW.  | R112                 | 19B800607P560 | Metal film: 56 ohms ±5%, 200 VDCW, 1/8 w.                  |
| and<br>C135  |                                |   | R113                 | 19B800607P220 | Metal film: 22 ohms <u>+</u> 5%, 200 VDC <b>W</b> , 1/8 w. |
| C136         | 19A702061P99                   | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30  | R114                 | 19A702931P388 | Metal film: 80.6K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.       |
| and<br>C137  |                                | PPM/°C.   | R115                 | 19B800607P680 | Metal film: 68 ohms ±5%, 200 VDCW, 1/8 w.                  |
| C138         | 19A701534P8                    | Tantalum: 0.47 uF <u>+</u> 20%, 35 VDCW.  | R116                 | 19B800607P103 | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.                 |
| C139         | 19A702061P99                   | Ceramic: 1000 pF <u>+</u> 5%, 50 VDCW, temp coef 0 <u>+</u> 30 PPM/°C.                  | and<br>R117          |               |  |
|              |                                | DIODES  | R118<br>thru<br>R120 | 19B800607P222 | Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.                |
| D101         | 19A700028P1                    | Silicon, fast recovery: fwd current 75 mA, 75   | R121                 | 19B800607P151 | Metal film: 150 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.         |
|              |                                | PIV; sim to Type 1N4148.  | R122                 | 19B800607P681 | Metal film: 680 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.         |
| D102         | 19A700085P2                    | Silicon; sim to MMBV109.  | and<br>R123          |               |  |
| D103         | 19A700047P2                    | Silicon.  | R124                 | 19B800607P100 | Metal film: 10 ohms ±5%, 200 VDCW, 1/8 w.                  |
| D104         | 19A700085P2                    | Silicon; sim to MMBV109.  | R125                 | 19B800607P562 | Metal film: 5.6K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.        |
| D105<br>and  | 19A116925P1                    | Silicon.  | thru<br>R129         |               |  |
| D106         |                                |   | R130                 | 19B800607P680 | Metal film: 68 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.          |
|              |                                |   | R131                 | 19B800607P222 | Metal film: 2.2K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.        |
| J101         | 19A703248P7                    | Contact, electrical. (Quantity 1-Groups 1,2,3).   | thru<br>R133         |               |  |
| J101         | 19A703248P17                   | Contact, electrical. (Groups 13,14,15).   | R134                 | 19B800607P221 | Metal film: 220 ohms ±5%, 200 VDCW, 1/8 w.                 |
| J102         | 19A703248P1                    | Contact, electrical. (Quantity 2).  | R135                 | 19B800607P820 | Metal film: 82 ohms ±5%, 200 VDCW, 1/8 w.                  |
| 1            |                                |   | R136                 | 19B800607P101 | Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.                 |
|              |                                |   | R137                 | 19B800607P820 | Metal film: 82 ohms ±5%, 200 VDCW, 1/8 w.                  |
| L101         | H343CLP10022                   | Coil, RF: 10.0 uH ±10%.   | R138                 | 19B800607P221 | Metal film: 220 ohms ±5%, 200 VDCW, 1/8 w.                 |
| L102         | 19B801196P202                  | Coil, RF: sim to Paul Smith SK-910.   |                      |               |  |
| L103<br>thru | H343CLP12922                   | Coil, RF: 1.2 uH ±10%.  | ł                    |               | INTEGRATED CIRCUITS  |
| L105         |                                |   | U101                 | 19B800902P1   | SYNTHESIZER: CMOS SERIAL INPUT.                            |
| L106         | 19A700024P4                    | Coil, RF: 180 nH ±10%.  | U102                 | 19A703091P1   | DIVIDER.   |
| L106         | 19A700024P5                    | Coil, RF: 220 nH ±10%.  | U103                 | 19A700029P44  | Digital: BILATERAL SWITCH.                                 |
| L106         | 19A700024P3                    | Coil, RF: 1.0 uH ±10%.  |                      | İ             |  |
| L107         | H343CLP12922                   | Coil, RF: 1.2 uH ±10%.  |                      |               | REFERENCE OSCILLATOR                                       |
|              |                                |   |                      |               |  |
| P151         | 19A701785P3                    | Contact, electrical. (Groups 1,2 & 3).  | C201                 | 19A703314P4   | Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to           |
| P151         | 19A701785P13                   | Contact, electrical. (Groups 13,14,15).   |                      |               | Panasonic LS Series.                                       |
| P152         | 19A702104P1                    | Receptacel: 2 position, shorting, rated at 3  | C202                 | 19A702248P304 | Ceramic: 39 pF +5%, 50 VDCW, N470 +60 PPM.                 |
|              |                                | amps; sim to Berg 65474-002.  | C203                 | 19A702061P99  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.     |
|              |                                |   | C204                 | 19A702061P43  | Ceramic: 43 pF ±5%, 50 VDCW, temp coef 0 ±30               |
| Q102         | 19A700059P2                    | Silicon, PNP.   | İ                    |               | PPM/°C.  |
| thru<br>Q104 |                                |   | C205                 | 19A702061P73  | Ceramic: 330 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.      |
| Q105         | 19A702524P2                    | N-Type, field effect; sim to MMBFU310.  | C208                 | 19A702061P57  | Ceramic: 82 pF ±5%, 50 VDCW, temp coef 0 ±30               |
| Q106         | 19A701808P2                    | Silicon, NPN; sim to MPS 6595.  |                      |               | PPM/°C.  |
| and<br>Q107  |                                |   | C209                 | 19A702052P20  | Ceramic: 0.033 uF ±10%, 50 VDCW.                           |
| Q108         | 19A700023P2                    | Silicon, NPN: sim to 2N3904.  | C210                 | 19A702061P99  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.     |
| and<br>Q109  |                                |   | C213                 | 19A702061P61  | Ceramic: 100 pF ±5%, 50 VDCW, temp coef 0 ±30              |
|              |                                | RESISTORS   |                      |               | PPM/°C.  |
|              | 1000000000000000               | Metal film: 22 ohms +5%, 200 VDCW, 1/8 w.   | 1                    |               |  |
| R101         | 19B800607P220                  | Metal film: 220 chms +5%, 200 vbcw, 1/6 w.  Metal film: 220K ohms +5%, 200 VbcW, 1/8 w. | D201                 | 19A700085P3   | Silicon, capacitive.                                       |
| R102         | 19B800607P224                  |   | D202                 | 19A700028P1   | Silicon, fast recovery: fwd current 75 mA, 75              |
| R103         | 19A702931P388                  | Metal film: 80.6K ohms ±1%, 200 VDCW, 1/8 w.  |                      |               | PIV; sim to Type 1N4148.                                   |
| R105<br>and  | 19B800607P122                  | Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.   | ı                    |               |  |
| R106         | 100000000000                   | Manal Silm. SC ohmo JES 2000 UDOW 1/0   | L201                 | 19B801161P2   | Coil, RF: sim to Standex EF-247.                           |
| R107         | 19B800607P560                  | Metal film: 56 ohms ±5%, 200 VDCW, 1/8 w.   | L202                 | 19A700024P29  | Coil, RF: 22 uH ±10%.                                      |
| R108         | 19B800607P100                  | Metal film: 10 ohms ±5%, 200 VDCW, 1/8 w.   |                      |               |  |
| R109         | 19B800607P105                  | Metal film: 1M ohms ±5%, 200 VDCW, 1/8 w.   |                      |               | TRANSISTORS  |
| R110         | 19B800607P273<br>19B800607P103 | Metal film: 27K ohms ±5%, 200 VDCW, 1/8 w.  | Q201                 | 19A700060P3   | N-Type, field effect; sim to J310.                         |
| R111         | 198800607P103                  | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  |                      |               |  |
|              |                                |   |                      |               |  |
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| SYMBOL              | GE PART NO.                   | DESCRIPTION  | SYMBOL       | GE PART NO.                | DESCRIPTION  | SYMBOL                 | GE PART NO.                    | DESCRIPTION   |
|---------------------|-------------------------------|--|--------------|----------------------------|--|------------------------|--------------------------------|---|
|                     |                               |  |              |                            |  | R702                   | 19B800607P272                  | Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.   |
|                     |                               | RESISTORS  |              |                            | RESISTORS  | R703                   | 19A702931P358                  | Metal film: 39.2K ohms <u>+</u> 10%, 200 VDCW, 1/8 w.                                     |
| R201                | 19A701250P354                 | Metal film: 35.7K ohms <u>+</u> 1%,250 VDCW, 1/4 w.  | R301<br>R302 | H212CRP322C                | Deposited carbon: 22K ohms ±5%, 1/4 w.   | R704                   | 19B800607P103                  | Metal film: 10K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  |
| R202                | 19A701250P288                 | Metal film: 8060 ohms <u>+</u> 1%, 250 VDCW, 1/4 w.  | R302         | H212CRP356C<br>H212CRP322C | Deposited carbon: 56K ohms ±5%, 1/4 w.   | R705                   | 19B800607P154                  | Metal film: 150K ohms ±5%, 200 VDCW, 1/8 w.   |
| R203<br>and         | 19A703813P1                   | Thermal: 5K ohms ±2%; sim to Midwest Components P1H-502.                                   | R304         | H212CRP133C                | Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 330 ohms ±5%, 1/4 w. | R706                   | 19B800607P103                  | Metal film: 10K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  |
| R204                |                               | P1n-302.   | R305         | 19A701250P369              | Metal film: 51.1K ohms ±1%, 1/4 w.   | R707                   | 19A702931P388                  | Metal film: 80.6K ohms ±1%, 200 VDCW, 1/8 w.  |
| R205                | 19A701250P193                 | Metal film: 909 ohms <u>+</u> 1%, 250 VDCW, 1/4.   | R306         | 19A701250P303              | Metal film: 10.5K ohms ±1%, 1/4 w.   | R708                   | 19A702931P358                  | Metal film: 39.2K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                      |
| R206                | 19A703813P2                   | Thermal: 20K ohms ±2%; sim to Midwest Components P1H-203                                   | R307         | 19A701250P278              | Metal film: 6.34K ohms ±1%, 1/4 w.   | R709                   | 19A702931P383                  | Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.  |
| R207                | 19A702931P317                 | Metal film: 14.7K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                       | and<br>R308  |                            | - ' '  | R710                   | 19A702931P384                  | Metal film: 73.2K ohms ±1%, 200 VDCW, 1/8 w.  |
| R208                | 19B800607P104                 | Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  | R309         | 19A701250P303              | Metal film: 10.5K ohms <u>+</u> 1%, 1/4 w.                                     | R711<br>R712           | 19A702931P383<br>19A702931P391 | Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.  |
| R209                | 19B800607P103                 | Metal film: 10K chms <u>+</u> 5%, 200 VDCW, 1/8 w.   | R310         | 19A143400P38               | Deposited carbon: 1.3K ohms ±5%, 1/4 w.  | R712                   | 19B800607P272                  | Metal film: 86.6K ohms ±1%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w. |
| R210                | 19B800607P122                 | Metal film: 1.2K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  | R311         | H212CRP247C                | Deposited carbon: 4.7K ohms ±5%, 1/4 w.  | R714                   | 19B800607P182                  | Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 W.  Metal film: 1.8K ohms ±5%, 200 VDCW, 1/8 W.  |
| R211                | 19B800607P181                 | Metal film: 180 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.   | R312         | H212CRP347C                | Deposited carbon: 47K ohms <u>+</u> 5%, 1/4 w.                                 | R715                   | 19B800607P473                  | Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  |
| R212                | 19B800784P106                 | Variable: 5K ohms ±20%, 1/2 w.   | R313         | 19A701250P330              | Metal film: 20K ohms ±1%, 1/4 w.   | R716                   | 19B800607P681                  | Metal film: 680 ohms ±5%, 200 VDCW, 1/8 w.  |
| R213                | 19B800607P100                 | Metal film: 10 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  | R314         | 19A701250P310              | Metal film: 12.4K ohms ±1%, 1/4 w.   | R717                   | 19A702931P325                  | Metal film: 17.8K ohms ±1%, 200 VDCW, 1/8 w.  |
| R214                | 19B800607P222                 | Metal film: 2.2K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  | R315         | 19A701250P350              | Metal film: 32.4K ohms ±1%, 1/4 w.   | R718                   | 19A702931P383                  | Metal film: 71.5K ohms ±1%, 200 VDCW, 1/8 w.  |
|                     |                               |  | R317         | H212CRP310C                | Deposited carbon: 10K ohms ±5%, 1/4 w.   | R719                   | 19A702931P382                  | Metal film: 69.8K ohms ±1%, 200 VDCW, 1/8 w.  |
| XY201               | 19A702742P1                   | Crystal socket. (Quantity 2).  | R319         | 19B800607P273              | Metal film: 27K ohms ±5%, 200 VDCW, 1/8 w.                                     | R720                   | 19A702931P383                  | Metal film: 71.5K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                      |
| Ì                   |                               | ·  | R320         | 19B800784P106              | Variable: 5K ohms ±20%, 1/2 w.   | R721                   | 19A702931P350                  | Metal film: 32.4K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                      |
|                     |                               |  | R321         | 19B800607P103              | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.                                     | R722                   | 19B800607P471                  | Metal film: 470 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  |
| Y201                | 19A703049G1                   | Quartz: 13.200 MHz.  |              |                            |  | R723                   | 19B800607P103                  | Metal film: 10K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  |
|                     |                               | The AUDIO  | U301         | 19A700086P4                | Operation Amplifier, Dual OP AMP; sim to 4558                                  | R724                   | 19B800784P108                  | Variable: 10K ohms $\pm 20\%$ , 1/2 w.  |
|                     |                               | Tx AUDIO   |              |                            | Type.  | R725                   | 19A702931P388                  | Metal film: 80.6K ohms ±1%, 200 VDCW, 1/8 w.  |
|                     |                               |  |              |                            | CHANNEL GUARD  | R726                   | 19A702931P358                  | Metal film: 39.2K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                      |
| C301                | 19A700235P16                  | Ceramic: 18 pF ±5%, 50 VDCW.   |              |                            |  | R727                   | 19A702931P317                  | Metal film: 14.7K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                      |
| C302                | 19A702250P211                 | Polyester: 0.47 uF <u>+</u> 5%, 50 VDCW.   | C701         | 19A703314P4                | Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to                               | R728                   | 19B800607P103                  | Metal film: 10K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  |
| C303<br>and         | 19A703314P10                  | Electrolytic: 10 uF -10+50% tol, 50 VDCW; sim to Panasonic LS Series.                      | and<br>C702  |                            | Panasonic LS Series.   | R729                   | 19B800607P122                  | Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.   |
| C304                |                               |  | C703         | 19A703314P10               | Electrolytic: 10 uF -10+50% tol, 50 VDCW; sim to                               | R730<br>R736           | 19B800607P681<br>19B800607P223 | Metal film: 680 ohms ±5%, 200 VDCW, 1/8 w.  |
| C305                | 19A701534P8                   | Tantalum: 0.47 uF ±20%, 35 VDCW.   | C704         | T644ACP368J                | Panasonic LS Series.  Polyester: 0.068 uF ±5%, 50 VDCW.                        | R737                   | 19A702931P317                  | Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 14.7K ohms ±1%, 200 VDCW, 1/8 w.  |
| C306<br>C307        | 19A702250P212<br>19A703314P10 | Polyester: 0.68 uF <u>+</u> 5%, 50 VDCW.  Electrolytic: 10 uF -10+50% tol, 50 VDCW; sim to | C705         | T644ACP333J                | Polyester: 0.033 uF ±5%, 50 VDCW.  | R738                   | 19A702931P321                  | Metal film: 16.2K ohms ±1%, 200 VDCW, 1/8 w.  |
| 0307                | 138700314F10                  | Panasonic LS Series.   | C706         | 19A701534P2                | Tantalum: 0.22 uF ±20%, 35 VDCW.   | R739                   | 19B800607P223                  | Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  |
| C308                | T644ACP268J                   | Polyester: .0068 uF ±5%, 50 VDCW.  | C707         | T644ACP333J                | Polyester: 0.033 uF ±5%, 50 VDCW.  | R740                   | 19A702931P305                  | Metal film: 11K ohms ±1%, 200 VDCW, 1/8 w.  |
| C309                | T644ACP210J                   | Polyester: .0010 uF ±5%, 50 VDCW.  | C708         | T644ACP368J                | Polyester: 0.068 uF ±5%, 50 VDCW.  | R741                   | 19A702931P322                  | Metal film: 16.5K ohms ±1%, 200 VDCW, 1/8 w.  |
| C310<br>and         | 19A700233P2                   | Ceramic, disc: 100 pF ±20%, 50 VDCW.   | C709         | T644ACP310J                | Polyester: .010 uF ±5%, 50 VDCW.   | R742                   | 19B800607P473                  | Metal film: 47K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  |
| C311                |                               |  | and<br>C710  |                            |  | R743                   | 19A702931P284                  | Metal film: 7320 ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                       |
| C312                | T644ACP315K                   | Polyester: .015 uF ±10%, 50 VDCW.  | C711         | T644ACP333J                | Polyester: 0.033 uF <u>+</u> 5%, 50 VDCW.                                      | R744                   | 19A702931P317                  | Metal film: 14.7K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                      |
| C313                | T644ACP310K                   | Polyester: .010 uF ±10%, 50 VDCW.  | and<br>C712  |                            |  | R745                   | 19A702931P151                  | Metal film: 332 ohms <u>+</u> 1%, 250 VDCW, 1/8 w.  |
|                     |                               | DIODES   | C713         | 19A702250P113              | Polyester: 0.1 uF ±10%, 50 VDCW.   | R746                   | 19A702931P309                  | Metal film: 12.1K ohms ±1%, 200 VDCW, 1/8 w.  |
| D301<br>and         | 19A700028P1                   | Silicon, fast recovery: fwd current 75 mA, 75<br>PIV; sim to Type 1N4148.                  | C715<br>thru | T644ACP310J                | Polyester: .01 uF ±5%, 50 VDCW.  | R747                   | 19A702931P289                  | Metal film: 8250 ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                       |
| D302                |                               | Tit, Sim to type INTIO   | C717         |                            |  | R748                   | 19A702931P358                  | Metal film: 39.2K ohms <u>+</u> 1%, 200 VDCW, 1/8 w.                                      |
|                     |                               |  | C718         | 19A703314P4                | Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.          |                        |                                |   |
| J301<br>and<br>J302 | 19A703248P7                   | Contact, electrical. (Quantity 1 each). (Groups 1,2,3).                                    | C719         | 19A703314P5                | Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.          | TP703<br>thru<br>TP705 |                                | Part of printed board 19D901204P1.  |
| J301                | 19A703248P17                  | Contact, electrical. (Groups 13,14,15).  | Ì            |                            |  |                        |                                | INTEGRATED CIRCUITS   |
| and<br>J302         |                               |  | D701         | 19A700028P1                | Silicon, fast receover: fwd current 75 mA, 75                                  | U701                   | 19A701789P1                    | Linear, Low Power OP AMP; sim to LM324N.  |
|                     |                               |  | thru<br>D704 |                            | PIV; sim to Type 1N4148.   | and<br>U702            |                                |   |
|                     |                               |  |              |                            |  | U703                   | 19A700086P2                    | DUAL OP AMP; sim to Type 1458.  |
| P301                | 19A701785P3                   | Contact, electrical. (Groups 1,2 & 3).   | Q701         | 19A700023P2                | Stilder NDW TRANSISTORS  | U704                   | 19A700029P44                   | Digital: BILATERAL SWITCH.  |
| P301                | 19A701785P13                  | Contact, electrical. (Groups 13,14,15).  | Q701<br>Q702 | 19A700023P2                | Silicon, NPN: sim to 2N3904. Silicon, NPN.                                     |                        | l                              |   |
|                     |                               |  | 1            |                            |  | W701                   | H212CRP910C                    | Deposited carbon: 1 ohms ±5%, 1/4 w.  |
| Q301                | 19A700023P2                   | Silicon, NPN: sim to 2N3904.   |              |                            | RESISTORS  | "."                    |                                |   |
|                     |                               |  | R701         | 19A702931P358              | Metal film: 39.2K ohms ±10%, 200 VDCW, 1/8 w.                                  |                        |                                |   |
|                     |                               |  |              |                            |  |                        |                                |   |
|                     |                               |  |              |                            |  |                        |                                |   |
|                     |                               |  |              |                            |  |                        |                                |   |
|                     |                               |  |              |                            |  |                        |                                |   |
|                     |                               | **************************************   |              |                            | <del></del>  |                        |                                |   |

| C802 1:  C803 1:  C804 1:  C805 Ti  C806 1:  C807 1:  C808 1:  C809 1:  C810 1:  C811 1:  C812 1:  C812 1:  C813 and  C814 1:  D801 1:  thru D809 D809 D811 1:  thru D814 D815 and D816 D817 1:  D818 1:  D819 1:    | 19A700235P15 19A703314P5 19A701534P3 19A701534P4 T644ACP310K 19A703314P4 19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702061P99  19A700028P1 19A700028P1 19A700028P1 19A700028P1  | SYSTEM CONTROL  | R803 R804 R805 R806 R807 R808 thru R810 R811 R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R836 R837 R838 | 19B800607P222 19B800607P473 19B800607P104 19B800607P101 19B800607P103 19B800607P104 19B800607P104 19B800607P471 19B800607P471 19B800607P471 19B800607P103 19B800607P103 19B800607P103 19B800607P103 19B800607P103 19B800607P103            | Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.0K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w. | C901 C902 C903 C904 and C905 C906 C907 thru C914 C915 and C916 D901 and D902 H902 | 19A701225P3 19A701225P3 19A703314P4 19A700233P6 19A702061P99 19A702052P3 19A702061P99 T324ADP1041 19A134354P9 19A134354P3 | SYSTEM   |
|--|---|---|---|--|---|---|---|--|
| C802 1:  C803 1:  C804 1:  C804 1:  C805 Tr  C806 1:  C807 1:  C808 1:  C809 1:  C810 1:  C811 1:  C812 1:  C812 1:  C813 and C814 1:  D801 1:  thru D809 D811 1:  thru D814 D815 and D816 D817 1:  D818 1:  D819 1: | 19A703314P5  19A701534P3  19A701534P4  T644ACP310K  19A703314P4  19A702052P3  19A702052P3  19A702052P20  19A702052P3  19A702052P20  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3 | Ceramic: 15 pF ±5%, 50 VDCW.  Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Tantalum: 0.47 uF ±20%, 35 VDCW.  Tantalum: 1 uF ±20%, 35 VDCW.  Polyester: .010 uF ±10%, 50 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW.  Solicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148. | R805 R806 R807 R808 thru R810 R811 R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R836 R837                | 19B800607P104<br>19B800607P101<br>19B800607P103<br>19B800607P103<br>19B800607P223<br>19B800607P104<br>19B800607P471<br>19B800607P471<br>19B800607P471<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P103 | Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | C902 C903 C904 and C905 C906 C907 thru C914 C915 and C916 D901 and D902 H902      | 19A703314P4  19A700233P6  19A703314P5  19A702061P99  19A702052P3  19A702061P99  T324ADP1041  19A134354P9                  | Electrolytic: 220 uF, -10+50%, 25 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 680 pF ±20%, 50 VDCW.  Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 1000 pF ±5%, 50 VDCW.  |
| C802 1:  C803 1:  C804 1:  C804 1:  C805 Tr  C806 1:  C807 1:  C808 1:  C809 1:  C810 1:  C811 1:  C812 1:  C812 1:  C813 and C814 1:  D801 1:  thru D809 D811 1:  thru D814 D815 and D816 D817 1:  D818 1:  D819 1: | 19A703314P5  19A701534P3  19A701534P4  T644ACP310K  19A703314P4  19A702052P3  19A702052P3  19A702052P20  19A702052P3  19A702052P20  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3 | Ceramic: 15 pF ±5%, 50 VDCW.  Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Tantalum: 0.47 uF ±20%, 35 VDCW.  Tantalum: 1 uF ±20%, 35 VDCW.  Polyester: .010 uF ±10%, 50 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Series: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.   | R806 R807 R808 thru R810 R811 R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R837 R838                     | 19B800607P471 19B800607P103  19B800607P103  19B800607P223 19B800607P104 19B800607P471 19B800607P471 19B800607P473 19B800607P103 19B800607P103 19B800607P103 19B800607P103  | Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | C902 C903 C904 and C905 C906 C907 thru C914 C915 and C916 D901 and D902 H902      | 19A703314P4  19A700233P6  19A703314P5  19A702061P99  19A702052P3  19A702061P99  T324ADP1041  19A134354P9                  | Electrolytic: 220 uF, -10+50%, 25 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 680 pF ±20%, 50 VDCW.  Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 ppM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 ppM/°C.  Ceramic: 1000 pF ±5%, 50 VDCW.  |
| C802 1:  C803 1:  C804 1:  C804 1:  C805 Tr  C806 1:  C807 1:  C808 1:  C809 1:  C810 1:  C811 1:  C812 1:  C812 1:  C813 and C814 1:  D801 1:  thru D809 D811 1:  thru D814 D815 and D816 D817 1:  D818 1:  D819 1: | 19A703314P5  19A701534P3  19A701534P4  T644ACP310K  19A703314P4  19A702052P3  19A702052P3  19A702052P20  19A702052P3  19A702052P20  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3  19A702052P3 | Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Tantalum: 0.47 uF ±20%, 35 VDCW.  Tantalum: 1 uF ±20%, 35 VDCW.  Polyester: .010 uF ±10%, 50 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW.  Series: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.   | R807 R808 thru R810 R811 R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R835 R837                          | 19B800607P101 19B800607P223 19B800607P104 19B800607P471 19B800607P471 19B800607P473 19B800607P103 19B800607P103 19B800607P103 19B800607P103 19B800607P103  | Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | C902 C903 C904 and C905 C906 C907 thru C914 C915 and C916 D901 and D902 H902      | 19A703314P4  19A700233P6  19A703314P5  19A702061P99  19A702052P3  19A702061P99  T324ADP1041  19A134354P9                  | Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 680 pF ±20%, 50 VDCW.  Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C. |
| C803 1: C804 1: C805 Tr C806 1: C807 1: C808 1: C809 1: C810 1: C811 1: C812 1: C812 1: C813 and C814 1: D801 1: thru D809 D811 1: thru D814 D815 and D816 D817 1: D818 1: D819 1:                                   | 19A701534P3 19A701534P4 T644ACP310K 19A703314P4 19A702052P3 19A702052P3 19A702052P20 19A702052P3 19A702052P3 19A702052P1 19A702061P99 19A700028P1 19A700028P1   | Panasonic LS Series.  Tantalum: 0.47 uF ±20%, 35 VDCW.  Tantalum: 1 uF ±20%, 35 VDCW.  Polyester: .010 uF ±10%, 50 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/*C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.   | R808 thru R810 R811 R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R836 R837                               | 19B800607P103  19B800607P223 19B800607P104 19B800607P471 19B800607P473 19B800607P103 19B800607P103 19B800607P103 19B800607P103 19B800607P103   | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | C903 C904 and C905 C906 C907 thru C914 C915 and C916  D901 and D902 H902          | 19A700233P6 19A703314P5 19A702061P99 19A702052P3 19A702061P99 T324ADP1041 19A134354P9                                     | Panasonic LS Series.  Ceramic: 680 pF ±20%, 50 VDCW.  Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  |
| C804 1: C805 Tr C806 1: C807 1: C808 1: C809 1: C810 1: C812 1: C812 1: C813 1: C814 1: D801 1: thru D809 1: D811 1: D814 1: D815 1: D816 D817 1: D818 1: D819 1:  | 19A701534P4 T644ACP310K 19A703314P4  19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702061P99  19A700028P1 19A700028P1  | Tantalum: 0.47 uF ±20%, 35 VDCW.  Tantalum: 1 uF ±20%, 35 VDCW.  Polyester: .010 uF ±10%, 50 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/*C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.   | thru R810 R811 R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R836 R837                                    | 19B800607P223 19B800607P104 19B800607P471 19B800607P473 19B800607P471 19B800607P103 19B800607P103 19B800607P103 19B800607P103 19B800607P103  | Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | C904 and C905 C906 C907 thru C914 C915 and C916 D901 and D902 H902                | 19A703314P5  19A702061P99  19A702052P3  19A702061P99  T324ADP1041  19A134354P9  | Ceramic: 680 pF ±20%, 50 VDCW.  Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coer 0 ±30 pPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  |
| C804 1: C805 Tr C806 1: C807 1: C808 1: C809 1: C810 1: C812 1: C812 1: C813 1: C814 1: D801 1: thru D809 1: D811 1: D814 1: D815 1: D816 D817 1: D818 1: D819 1:  | 19A701534P4 T644ACP310K 19A703314P4  19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702052P3 19A702061P99  19A700028P1 19A700028P1  | Tantalum: 1 uF ±20%, 35 VDCW.  Polyester: .010 uF ±10%, 50 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.   | R811 R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R836 R837  | 19B800607P104<br>19B800607P471<br>19B800607P473<br>19B800607P471<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P222<br>19B800607P272<br>19B800607P272  | Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | and<br>C905<br>C906<br>C907<br>thru<br>C914<br>C915<br>and<br>C916                | 19A702061P99 19A702052P3 19A702061P99 T324ADP1041 19A134354P9   | Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  |
| C806 1:  C807 1:  C808 1:  C809 1:  C810 1:  C811 1:  C812 1:  C812 1:  C813 and  C814 1:  D801 1:  thru  D809 D811 1:  thru  D815 and  D816 D817 1:  D818 1:  D819 1:   | 19A703314P4  19A702052P3  19A702052P3  19A702052P20  19A702052P3  19A702051P99  19A702061P99  19A700028P1  19A700028P1  | Polyester: .010 uF ±10%, 50 VDCW.  Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 0.033 uF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  | R812 R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R836 R837   | 19B800607P104<br>19B800607P471<br>19B800607P473<br>19B800607P471<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P222<br>19B800607P272<br>19B800607P272  | Metal film: 100K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | C905 C906 C907 thru C914 C915 and C916 D901 and D902 H902                         | 19A702052P3  19A702061P99  T324ADP1041  19A134354P9   | Panasonic LS Series.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.   |
| C807 19 C808 19 C809 19 C810 19 C810 19 C811 19 C812 19 C813 and C814 19 D801 19 D801 19 D809 D D811 19 D815 and D816 D817 19 D818 19  | 19A702052P3<br>19A702052P3<br>19A702052P3<br>19A702052P20<br>19A702052P3<br>19A702061P99<br>19A700028P1<br>19A700028P1<br>19A700028P1   | Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/*C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 0.033 uF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.   | R813 R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R836 R837  | 19B800607P471 19B800607P473 19B800607P471 19B800607P103 19B800607P103 19B800607P103 19B800607P103 19B800607P222 19B800607P272 19B800607P271  | Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | C907 thru C914 C915 and C916  D901 and D902 H902                                  | 19A702052P3  19A702061P99  T324ADP1041  19A134354P9   | PPM/°C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.  DIODES  Rectifier, silicon; general purpose.  Optoelectronic: yellow: sim to Hew. Packard   |
| C808 19 C809 19 C810 and C811 C812 19 C813 and C814  D801 19 D809 19 D811 19 D814 19 D815 19 D816 D817 19 D818 19 D819 19  | 19A700235P9  19A702052P3  19A702052P20  19A702052P3  19A702061P99  19A700028P1  19A700028P1   | Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/*C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 0.033 uF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM.  | R814 R815 R816 R820 R822 R823 R826 thru R833 R835 R835 R836   | 19B800607P473<br>19B800607P471<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P103<br>19B800607P222<br>19B800607P272   | Metal film: 47K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | thru<br>C914<br>C915<br>and<br>C916<br>D901<br>and<br>D902                        | 19A702061P99  T324ADP1041  19A134354P9  | Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM/°C.  DIODES  Rectifier, silicon; general purpose.  Optoelectronic: yellow: sim to Hew. Packard  |
| C808 19 C809 19 C810 and C811 C812 19 C813 and C814  D801 19 D809 19 D811 19 D814 19 D815 19 D816 D817 19 D818 19 D819 19  | 19A700235P9  19A702052P3  19A702052P20  19A702052P3  19A702061P99  19A700028P1  19A700028P1   | Ceramic: 4.7 pF ±0.25 pF, 50 VDCW, temp coef N150 PPM/*C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 0.033 uF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM.  | R815 R816 R820 R822 R823 R826 thru R833 R835 R835 R837  | 19B800607P471 19B800607P103 19B800607P103 19B800607P103 19B800607P103 19B800607P222 19B800607P272 19B800607P271  | Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | thru<br>C914<br>C915<br>and<br>C916<br>D901<br>and<br>D902                        | 19A702061P99  T324ADP1041  19A134354P9  | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM/°C.  DIODES Rectifier, silicon; general purpose.  Optoelectronic: yellow: sim to Hew. Packard   |
| C809 11 C810 15 and C811 C812 15 C812 15 C813 and C814  D801 15 thru D809 D811 thru D815 and D816 D817 15 D818 15 D819 15  | 19A702052P3<br>19A702052P20<br>19A702052P3<br>19A702061P99<br>19A700028P1<br>19A700028P1<br>19A700028P1   | N150 PPM/*C.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 0.033 uF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.   | R816<br>R820<br>R822<br>R823<br>R826<br>thru<br>R833<br>R835<br>R836<br>R837  | 19B800607P103<br>19B800607P103<br>19B800607P122<br>19B800607P103<br>19B800607P103<br>19B800607P222<br>19B800607P272  | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | C915<br>and<br>C916<br>D901<br>and<br>D902  | T324ADP1041<br>19A134354P9  | PPM/°C.  DIODES  Rectifier, silicon; general purpose.  Optoelectronic: yellow: sim to Hew. Packard   |
| C810 15 and C811   | 19A702052P20<br>19A702052P3<br>19A702061P99<br>19A700028P1<br>19A700028P1<br>19A700028P1  | Ceramic: 0.033 uF ±10%, 50 VDCW.  Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM.   | R820<br>R822<br>R823<br>R826<br>thru<br>R833<br>R835<br>R836<br>R837  | 19B800607P103<br>19B800607P122<br>19B800607P103<br>19B800607P103<br>19B800607P222<br>19B800607P272   | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | and<br>C916<br>D901<br>and<br>D902<br>H902  | T324ADP1041<br>19A134354P9  | PPM/°C.  DIODES  Rectifier, silicon; general purpose.  Optoelectronic: yellow: sim to Hew. Packard   |
| And C811 C812 19 C812 19 C813 and C814 19 D801 19 thru D809  | 19A702052P3<br>19A702061P99<br>19A700028P1<br>19A700028P1<br>19A700028P1  | Ceramic: 470 pF ±10%, 50 VDCW.  Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 pPM.   | R822<br>R823<br>R826<br>thru<br>R833<br>R835<br>R836<br>R837  | 19B800607P122<br>19B800607P103<br>19B800607P103<br>19B800607P222<br>19B800607P272<br>19B800607P101   | Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | D901<br>and<br>D902<br>H902   | 19A134354P9   | Rectifier, silicon; general purpose.  Optoelectronic: yellow: sim to Hew. Packard  |
| C811  C812  18  C813  and  C814   D801  thru  D809  D811  thru  D814  D815  and  D816  D817  D818  D819  18  | 19A702061P99  19A700028P1  19A700028P1  19A700028P1   | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 ppM.  DIODES Silicon, fast recovery: fwd current 75 mA, 75 pIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 pIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 pIV; sim to Type 1N4148.  | R823<br>R826<br>thru<br>R833<br>R835<br>R836<br>R837  | 19B800607P103<br>19B800607P103<br>19B800607P222<br>19B800607P272<br>19B800607P101  | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | and<br>D902<br>H902   | 19A134354P9   | Rectifier, silicon; general purpose.  Optoelectronic: yellow: sim to Hew. Packard  |
| C813 and C814  | 19A702061P99  19A700028P1  19A700028P1  19A700028P1   | Ceramic: 1000 pF ±5%, 50 VDCW, temp coef 0 ±30 ppM.  DIODES Silicon, fast recovery: fwd current 75 mA, 75 pIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 pIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 pIV; sim to Type 1N4148.  | R826<br>thru<br>R833<br>R835<br>R836<br>R837  | 19B800607P103<br>19B800607P222<br>19B800607P272<br>19B800607P101   | Metal film: 10K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | and<br>D902<br>H902   | 19A134354P9   | Optoelectronic: yellow: sim to Hew. Packard  |
| D801 19 19 19 19 19 19 19 19 19 19 19 19 19  | 19A700028P1<br>19A700028P1<br>19A700028P1   | PPM.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  | thru<br>R833<br>R835<br>R836<br>R837  | 19B800607P222<br>19B800607P272<br>19B800607P101  | Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | D902<br>Н902  |   | Optoelectronic: yellow: sim to Hew. Packard HLMP4719. Part of 19A701522G9, G10.  |
| D801 15 15 15 and D816 D817 16 D818 15 D819 15   | 19A700028P1   | Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  | R835<br>R836<br>R837<br>R838  | 19B800607P272<br>19B800607P101   | Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | l   |   | Optoelectronic: yellow: sim to Hew. Packard<br>HLMP4719. Part of 19A701522G9, G10.   |
| thru D809  D811 thru D814  D815 and D816  D817  D818  15 D819  15  | 19A700028P1   | Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75   | R837<br>R838  | 19B800607P272<br>19B800607P101   | Metal film: 2.7K ohms ±5%, 200 VDCW, 1/8 w.  Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.   | н903  | 19A134354P3   |  |
| thru D809 D811 thru D814 D815 and D816 D817 D818 15 D819 15  | 19A700028P1   | Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75   | R837<br>R838  | 19B800607P101  | Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | i i   |   | Optoelectronic: green; sim to Hew. Packard   |
| thru D809 D811 thru D814 D815 and D816 D817 D818 15 D819 15  | 19A700028P1   | PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75   |   | 19B800607P122  | 1 · · · · · · · · · · · · · · · · · · ·   | ı   |   | 5082-4955. Part of 19A701522G9, G10.   |
| D811 15 15 15 15 15 15 15 15 15 15 15 15 1   | 19A700028P1   | PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75   | R840  |  | Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.   | Ì   |   |  |
| thru D814  D815 and D816  D817  D818  15 D819  15  | 19A700028P1   | PIV; sim to Type 1N4148.  Silicon, fast recovery: fwd current 75 mA, 75   | l l   | 19A702931P317  | Metal film: 14.7K ohms +1%, 200 VDCW, 1/8 w.  | J901  | 19J706214P4   | Connector: 4 contacts rated @ 7 amps; sim to   |
| and D816   |   |   | R841  | 19B800607P101  | Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  |   |   | Molex 09-67-1042. (Groups 1,2,3).  |
| D816  D817  D818  D819  19   | 19470002503   |   | R842  | 19B800607P122  | Metal film: 1.2K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.   | J901  | 19A116659P185   | Connector: 4 contacts rated @ 7 amps; sim to Molex 09-80-1045. (Groups 13,14,15).  |
| D818 19  | 194700025D3   | PIV; sim to Type 1N4148.  | R843  | 19B800607P103  | Metal film: 10K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  | J903  | 19J706214P7   | Flat wafer: 7 contacts rated @ 7 amps: sim to  |
| D819 19  | 15A100025F5   | Silicon, zener: 400 mW max; sim to BZX55-C3V3.  | R844  | 19B800607P471  | Metal film: 470 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  |   |   | Molex 09-67-1072. (Groups 1,2,3).  |
|  | 19A700025P8   | Silicon, zener: 400 mW max; sim to BZX55-C6V8.  | R848  | 19B800607P103  | Metal film: 10K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  | J903  | 19A116659P186   | Connector: 7 contacts rated @ 7 amps; sim to Molex 09-80-1075.   |
| н801 19  | 19A700028P1   | Silicon, fast recovery: fwd current 75 mA, 75   | thru<br>R851  |  |   | J904  | 19A703248P7   | Contact, electrical. (Quantity 2). (Groups   |
| 1801   | 19A134354P1   | PIV; sim to Type 1N4148.  | R852  | 19B800607P101  | Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.  | J904  | 19A703248P17  | 1,2,3).  |
|  | 19413433491   | Diode, optoelectronic: red; sim to Hew. Packard 5082-4655.  | R853  | 19B800607P562  | Metal film: 5.6K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.   | J905  | 19A703248P7   | Contact, electrical. (Groups 13,14,15).  Contact, electrical. (Quantity 1). (Groups  |
|  |   |   | R854  | 19B800607P103  | Metal film: 10K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.  | ""  | 100.10021011  | 1,2,3).  |
| J802 19  | 19A703248P7   | Contact, electrical. (Quantity 10). (Groups   | R861  | 19B800607P562  | Metal film: 5.6K ohms <u>+</u> 5%, 200 VDCW, 1/8 w.   | J905  | 19A703248P17  | Contact, electrical. (Groups 13,14,15).  |
|  | 101110011011  | 1,2,3).   | R862  | 19B800607P223  | Metal film: 22K ohms ±5%, 200 VDCW, 1/8 w.  | J906  | 19A703248P5   | Contact, electrical. (Quantity 12). (Groups 1,2,3).  |
| J802 19  | 19A703248P17  | Contact, electrical. (Groups 13,14,15).   | R863<br>and   | 19B800607P122  | Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.   | J906  | 19A703248P15  | Contact, electrical. (Groups 13,14,15).  |
| J806 19  | 19A703248P7   | Contact, electrical. (Quantity 1). (Groups 1,2,3).  | R864  |  |   | J910  | 19A116659P184   | Connector, printed wiring: 11 contacts; sim to   |
| J806 19  | 19A703248P17  | Contact, electrical. (Groups 13,14,15).   | R865  | 199B800607P222   | Metal film: 2.2K ohms ±5%, 200 VDCW.  |   |   | Molex 09-75-1116.  |
| J810 19  | 19A703248P7   | Contact, electrical. (Quantity 1 each). (Groups   |   | ]  |   | J911  | 19A116659P183   | Connector, printed wiring: 8 contacts; sim to Molex 09-75-1086.  |
| and<br>J811  |   | 1,2,3).   | U802  | 19A116968P3  | Linear, timer: DUAL IN-LINE 14 Pin Dip Package;   | J912  | 19J706214P4   | Connector: 4 contacts rated @ 7 amps; sim to   |
|  | 19A703248P17  | Contact, electrical. (Groups 13,14,15).   |   |  | sim to Signetics SA556N.  |   |   | Molex 09-67-1042. (Groups 1,2,3).  |
| and<br>J811  |   |   | U803  | 19J706032P1  | Linear: POSITIVE VOLTAGE REGULATOR; sim to MC7805CT.  | J912  | 19A116659P185   | Connector: 4 contacts rated @ 7 amps; sim to Molex 09-80-1045.   |
| J812 19  | 19A703248P7   | Contact, electrical. (Quantity 3). (Groups  | U804  | 19A116180P33   | Digital: HEX INVERTER BUFFER/DRIVER (OPEN   | J920  | 19A703248P7   | Contact, electrical. (Quantity 1 each). (Groups  |
|  | 10.5000.0015  | 1,2,3).   |   | 10170007000  | COLLECTOR).   | and<br>J921   |   | 1,2,3).  |
| J812 19  | 19A703248P17  | Contact, electrical. (Groups 13,14,15).   | U805  | 19A703072P2  | Digital: sim to XICOR X2212DI.  | J920  | 19A703248P17  | Contact, electrical. (Groups 13,14,15).  |
|  |   | TRANSISTORS   |   |  |   |   |   |  |
| Q802 19  | 19A700022P2   | Silicon, PNP: sim to 2N3906.  | W801  | H212CRP910C  | Deposited carbon: 1 ohms $\pm 5\%$ , 1/4 w.   | L901  | H343CLP12922  | Coil, RF: 1.2 uH +10%.   |
| Q803 19  | 19A700023P2   | Silicon, NPN: sim to 2N3904.  | İ   |  |   | 1501  | N343CLP12922  | Coll, RF: 1.2 un <u>+</u> 10%.   |
| Q806 19  | 19A700023P2   | Silicon, NPN: sim to 2N3904.  | XU801   | 19A700156P5  | Socket, integrated circuit: 40 contacts; sim to   |   |   |  |
| Q808   |   |   | A0001   | 134700130F0  | Augat 340-AG39D.  | P907  | 19A700102P10  | Printed wire: 3 contacts; sim to Molex 09-52-3032.   |
|  |   |   | XU805   | 19A700156P11   | Integrated circuit.   |   |   |  |
| R801 19  | 19A702931P325   | Metal film: 17.8K ohms ±1%, 200 VDCW, 1/8 w.  |   |  |   |   |   | TRANSISTORS  |
|  | 15 020011 020   | 111 111 111 111 111 111 111 111 111 11  | Y801  | 19A702511G3  | Quartz: 6.000000 MHz.   | Q901  | 19A116774P3   | Silicon, NPN; sim to Type 2N5210.  |

# LBI31349

| SYMBOL            | GE PART NO.   | DESCRIPTION  |
|-------------------|---------------|--|
|                   |               |  |
| R901              | 19B800607P561 | Metal film: 560 ohms ±5%, 200 VDCW, 1/8 w.                               |
| R902              | 19B800607P122 | Metal film: 1.2K ohms ±5%, 200 VDCW, 1/8 w.                              |
| R904              | 19A702931P350 | Metal film: 32.4K ohms ±1%, 200 VDCW, 1/8 w.                             |
| 1905              | 19A702931P358 | Metal film: 39.2K ohms ±1%, 200 VDCW, 1/8 w.                             |
| R906              | 19B800607P562 | Metal film: 5.6K ohms ±5%, 200 VDCW, 1/8 w.                              |
| 1907              | 19B800607P222 | Metal film: 2.2K ohms ±5%, 200 VDCW, 1/8 w.                              |
| 908               | 19B800607P561 | Metal film: 560 ohms <u>+</u> 5%, 200 VDCW, 1/8 w.                       |
| 909               | 19B800607P471 | Metal film: 470 ohms ±5%, 200 VDCW, 1/8 w.                               |
| 910               | 19B800607P221 | Metal film: 220 ohms ±5%, 200 VDCW, 1/8 w.                               |
| 911               | H212CRP122C   | Deposited carbon: 220 ohms $\pm 5\%$ , 1/4 w.                            |
| 912               | 19B800607P681 | Metal film: 680 ohms ±5%, 200 VDCW, 1/8 w.                               |
| 913               | 19B800607P101 | Metal film: 100 ohms ±5%, 200 VDCW, 1/8 w.                               |
| 914               | 198800607P681 | Metal film: 680 ohms ±5%, 200 VDCW, 1/8 w.                               |
| 915               | 19B800607P562 | Metal film: 5.6K ohms ±5%, 200 VDCW, 1/8 w.                              |
|                   |               |  |
| 901               | 19A700184P1   | Jumper.  |
| 901<br>hru<br>903 | 198,0010471   |  |
| 904<br>1ru<br>911 | H212CRP910C   | Deposited carbon: 1 ohms ±5%, 1/4 w.                                     |
|                   |               |  |
|                   | 19B800962P1   | Can. (L102).   |
|                   | 19A701516P1   | Insulator, plate. (Used with Y801).                                      |
|                   | 19B800952P1   | Support. (U803).   |
|                   | 19A702364P208 | Machine screw, metric: 2.545 x 10MM. (Secures                            |
|                   |               | U803).   |
|                   | 19A700068P1   | Insulator, bushing. (Used with U803).                                    |
|                   | 19A700115P3   | Insulator, plate. (Used with U803).                                      |
|                   |               | ASSOCIATED PARTS   |
| 301               | 19A703244P1   | Microcomputer: HMOS, 8-bit. (Used in radios without Dual Priority Scan). |
| 01                | 19A703754G4   | Microcomputer: HMOS, 8-bit. (Used in radios with Dual Priority Scan).    |
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# **PRODUCTION CHANGES**

REV. A - SYNTHESIZER/INTERCONNECT BOARD 19D901205G1-3

To improve tuning range of Reference oscillator. Changed C204 from 39pF to 43pF. Old part number is: C204-19A702061P41-Ceramic:39pF±5%, 50 vdcw,

temp coef

temp coef 0 ± 30 PPM.

REV. B - Consolidates changes to improve overall performance and assembly.

Removed W302 and W201

Removed R322 Added P152 and J102 Changed R713 from 2.2K

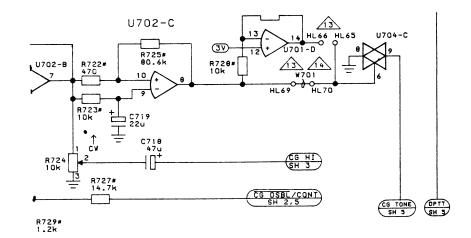
to 2.7K

Added D814 Changed R714 from 1.2K

to 1.8K

Added R701, R703, R716, R730 and Q702

# OLD SCHEMATIC WAS:



REV. C - SYNTHESIZER/INTERCONNECT BOARD 19D901205G1-3

To improve operation of micro. Added R865.

REV. D - To prevent improper reset causing masked micro to lose memory. Removed D809.

D809 was: 19A700028P1 - Silicon, Fast Recovery Fwd current 75 mA, 75 pIV. Sim to Type 1N4148.

REV. E - To improve over-all operation. Removed H801, R806, P152, and added C714 between CG HI and R312. Positive side to CG HI. R806 was: 19B800607P471 - Metal Film: 470  $\Omega$   $\pm 5\%$ , 1/8 w.

REV. F - SYNTHESIZER/INTERCONNECT BOARD 19D901205G1-3

To improve electrostatic discharge protection of U704. Added D701-D704. See revised schematics.